

# DS90C031B LVDS Quad CMOS Differential Line Driver

Check for Samples: DS90C031B

## FEATURES

- >155.5 Mbps (77.7 MHz) switching rates
- High impedance LVDS outputs with power-off
- ±350 mV differential signaling
- Ultra low power dissipation
- 400 ps maximum differential skew (5V, 25°C)
- 3.5 ns maximum propagation delay
- Industrial operating temperature range
- Pin compatible with DS26C31, MB571 (PECL) and 41LG (PECL)
- Conforms to ANSI/TIA/EIA-644 LVDS standard
- Offered in narrow body SOIC package
- Fail-safe logic for floating inputs

## DESCRIPTION

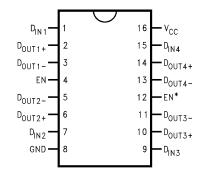
The DS90C031B is a quad CMOS differential line driver designed for applications requiring ultra low power dissipation and high data rates. The device supports data rates in excess of 155.5 Mbps (77.7 MHz) and uses Low Voltage Differential Signaling (LVDS) technology.

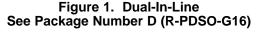
The DS90C031B accepts TTL/CMOS input levels and translates them to low voltage (350 mV) differential output signals. In addition the driver supports a TRI-STATE function that may be used to disable the output stage, disabling the load current, and thus dropping the device to an ultra low idle power state of 11 mW typical.

In addition, the DS90C031B provides power-off high impedance LVDS outputs. This feature assures minimal loading effect on the LVDS bus lines when  $V_{CC}$  is not present.

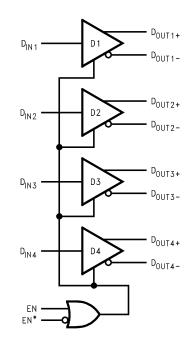
The DS90C031B and companion line receiver (DS90C032B) provide a new alternative to high power pseudo-ECL devices for high speed point-to-point interface applications.

## **Connection Diagram**





## **Functional Diagram**



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners. SNLS051B-MARCH 1999-REVISED MARCH 2013

#### Driver Truth Table

Ena	bles	Input	Out	puts
EN	EN*	D <sub>IN</sub>	D <sub>OUT+</sub>	D <sub>OUT-</sub>
L	Н	Х	Z	Z
All other combina	tions of ENABLE	L	L	Н
inp	uts	Н	Н	L



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings <sup>(1)</sup>

-0.3V to +6V
-0.3V to (V <sub>CC</sub> + 0.3V)
-0.3V to (V <sub>CC</sub> + 0.3V)
-0.3V to +5.8V
Continuous
1068 mW
8.5 mW/°C above +25°C
−65°C to +150°C
+260°C
+150°C
≥ 2kV
≥ 250V

(1) "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" specifies conditions of device operation.

### **Recommended Operating Conditions**

	Min	Тур	Max	Units
Supply Voltage (V <sub>CC</sub> )	+4.5	+5.0	+5.5	V
Operating Free Air Temperature (T <sub>A</sub> )	-40	+25	+85	°C

www.ti.com



#### **Electrical Characteristics**

Over supply voltage and operating temperature ranges, unless otherwise specified. (1) (2)

Symbol	Parameter	Test Conditions	Pin	Min	Тур	Max	Units
V <sub>OD1</sub>	Differential Output Voltage	$R_L = 100\Omega$ (Figure 2)	D <sub>OUT</sub> -,	250	345	450	mV
$\Delta V_{OD1}$	Change in Magnitude of V <sub>OD1</sub> for Complementary Output States		D <sub>OUT+</sub>		4	35	mV
V <sub>OS</sub>	Offset Voltage			1.10	1.25	1.35	V
ΔV <sub>OS</sub>	Change in Magnitude of V <sub>OS</sub> for Complementary Output States				5	25	mV
V <sub>OH</sub>	Output Voltage High	$R_L = 100\Omega$			1.41	1.60	V
V <sub>OL</sub>	Output Voltage Low			0.90	1.07		V
VIH	Input Voltage High		D <sub>IN</sub> ,	2.0		V <sub>CC</sub>	V
V <sub>IL</sub>	Input Voltage Low		EN, EN*	GND		0.8	V
l <sub>l</sub>	Input Current	$V_{IN} = V_{CC}$ , GND, 2.5V or 0.4V		-10	±1	+10	μA
V <sub>CL</sub>	Input Clamp Voltage	I <sub>CL</sub> = −18 mA		-1.5	-0.8		V
l <sub>os</sub>	Output Short Circuit Current	$V_{OUT} = 0V^{(3)}$	D <sub>OUT-</sub> ,		-3.5	-5.0	mA
I <sub>OZ</sub>	Output TRI-STATE Current	$EN = 0.8V$ and $EN^* = 2.0V$ , $V_{OUT} = 0V$ or $V_{CC}$	D <sub>OUT+</sub>	-10	±1	+10	μA
I <sub>OFF</sub>	Power - Off Leakage	$V_0 = 0V$ or 2.4V, $V_{CC} = 0V$ or Open		-10	±1	+10	μA
I <sub>CC</sub>	No Load Supply Current Drivers	$D_{IN} = V_{CC}$ or GND	V <sub>CC</sub>		1.7	3.0	mA
	Enabled	D <sub>IN</sub> = 2.5V or 0.4V			4.0	6.5	mA
I <sub>CCL</sub>	Loaded Supply Current Drivers Enabled	$R_L = 100\Omega$ (all channels), $V_{IN} = V_{CC}$ or GND (all inputs)			15.4	21.0	mA
I <sub>CCZ</sub>	No Load Supply Current Drivers Disabled	$D_{IN} = V_{CC}$ or GND, EN = GND, EN* = V <sub>CC</sub>			2.2	4.0	mA

Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except: V<sub>OD1</sub> and ΔV<sub>OD1</sub>.
All typicals are given for: V<sub>CC</sub> = +5.0V, T<sub>A</sub> = +25°C.
Output short circuit current (I<sub>OS</sub>) is specified as magnitude only, minus sign indicates direction only.

SNLS051B-MARCH 1999-REVISED MARCH 2013



www.ti.com

### Switching Characteristics

 $V_{CC} = +5.0V, T_{A} = +25^{\circ}C^{(1)(2)(3)}$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PHLD</sub>	Differential Propagation Delay High to Low	$R_{L} = 100\Omega, C_{L} = 5 \text{ pF}$	1.0	2.0	3.0	ns
t <sub>PLHD</sub>	Differential Propagation Delay Low to High	(Figure 3 and Figure 4)	1.0	2.1	3.0	ns
t <sub>SKD</sub>	Differential Skew  t <sub>PHLD</sub> - t <sub>PLHD</sub>		0	80	400	ps
t <sub>SK1</sub>	Channel-to-Channel Skew (4)		0	300	600	ps
t <sub>TLH</sub>	Rise Time			0.35	1.5	ns
t <sub>THL</sub>	Fall Time			0.35	1.5	ns
t <sub>PHZ</sub>	Disable Time High to Z	$R_{L} = 100\Omega, C_{L} = 5 \text{ pF}$		2.5	10	ns
t <sub>PLZ</sub>	Disable Time Low to Z	(Figure 5 and Figure 6)		2.5	10	ns
t <sub>PZH</sub>	Enable Time Z to High			2.5	10	ns
t <sub>PZL</sub>	Enable Time Z to Low			2.5	10	ns

(1) All typicals are given for:  $V_{CC} = +5.0V$ ,  $T_A = +25^{\circ}C$ . (2) Generator waveform for all tests unless otherwise specified: f = 1 MHz,  $Z_O = 50\Omega$ ,  $t_r \le 6$  ns, and  $t_f \le 6$  ns.

(3) C<sub>L</sub> includes probe and jig capacitance.

(4) Channel-to-Channel Skew is defined as the difference between the propagation delay of the channel and the other channels in the same chip with an event on the inputs.

### **Switching Characteristics**

 $V_{CC}$  = +5.0V ± 10%,  $T_{A}$  = -40°C to +85°C  $^{(1)}$   $^{(2)}$   $^{(3)}$ 

Symbol	Parameter	Conditions	Min	Тур	Мах	Units
t <sub>PHLD</sub>	Differential Propagation Delay High to Low	$R_{L} = 100\Omega, C_{L} = 5 \text{ pF}$	0.5	2.0	3.5	ns
t <sub>PLHD</sub>	Differential Propagation Delay Low to High	(Figure 3 and Figure 4)	0.5	2.1	3.5	ns
t <sub>SKD</sub>	Differential Skew  t <sub>PHLD</sub> - t <sub>PLHD</sub>		0	80	900	ps
t <sub>SK1</sub>	Channel-to-Channel Skew <sup>(4)</sup>		0	0.3	1.0	ns
t <sub>SK2</sub>	Chip to Chip Skew <sup>(5)</sup>				3.0	ns
t <sub>TLH</sub>	Rise Time			0.35	2.0	ns
t <sub>THL</sub>	Fall Time			0.35	2.0	ns
t <sub>PHZ</sub>	Disable Time High to Z	$R_L = 100\Omega, C_L = 5 \text{ pF}$		2.5	15	ns
t <sub>PLZ</sub>	Disable Time Low to Z	(Figure 5 and Figure 6)		2.5	15	ns
t <sub>PZH</sub>	Enable Time Z to High			2.5	15	ns
t <sub>PZL</sub>	Enable Time Z to Low			2.5	15	ns

(1) All typicals are given for:  $V_{CC}$  = +5.0V,  $T_A$  = +25°C.

(2) Generator waveform for all tests unless otherwise specified: f = 1 MHz,  $Z_0 = 50\Omega$ ,  $t_r \le 6 \text{ ns}$ , and  $t_f \le 6 \text{ ns}$ .

C<sub>L</sub> includes probe and jig capacitance. (3)

Channel-to-Channel Skew is defined as the difference between the propagation delay of the channel and the other channels in the (4) same chip with an event on the inputs.

Chip to Chip Skew is defined as the difference between the minimum and maximum specified differential propagation delays. (5)



#### SNLS051B-MARCH 1999-REVISED MARCH 2013

### PARAMETER MEASUREMENT INFORMATION

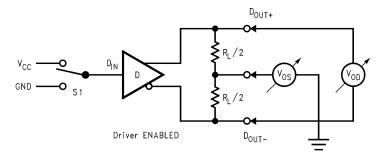


Figure 2. Driver  $V_{OD}$  and  $V_{OS}$  Test Circuit

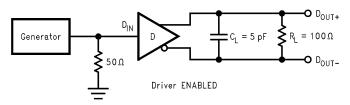


Figure 3. Driver Propagation Delay and Transition Time Test Circuit

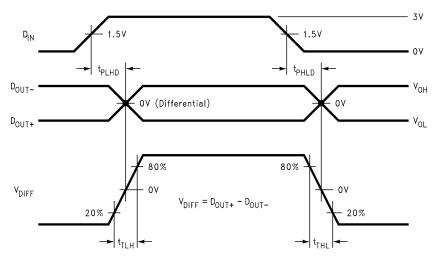


Figure 4. Driver Propagation Delay and Transition Time Waveforms

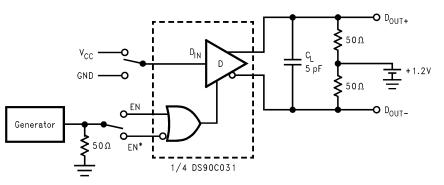
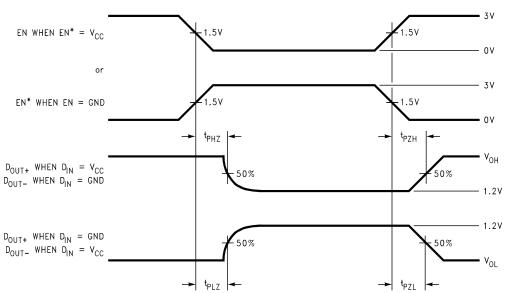


Figure 5. Driver TRI-STATE Delay Test Circuit

SNLS051B-MARCH 1999-REVISED MARCH 2013







## **Typical Application**

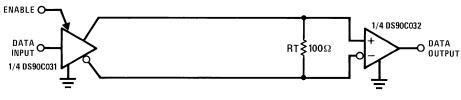


Figure 7. Point-to-Point Application



#### SNLS051B-MARCH 1999-REVISED MARCH 2013

### **APPLICATIONS INFORMATION**

LVDS drivers and receivers are intended to be primarily used in an uncomplicated point-to-point configuration as is shown in Figure 7. This configuration provides a clean signaling environment for the quick edge rates of the drivers. The receiver is connected to the driver through a balanced media which may be a standard twisted pair cable, a parallel pair cable, or simply PCB traces. Typically, the characteristic impedance of the media is in the range of  $100\Omega$ . A termination resistor of  $100\Omega$  should be selected to match the media, and is located as close to the receiver input pins as possible. The termination resistor converts the current sourced by the driver into a voltage that is detected by the receiver. Other configurations are possible such as a multi-receiver configuration, but the effects of a mid-stream connector(s), cable stub(s), and other impedance discontinuities as well as ground shifting, noise margin limits, and total termination loading must be taken into account.

The DS90C031B differential line driver is a balanced current source design. A current mode driver, generally speaking has a high output impedance and supplies a constant current for a range of loads (a voltage mode driver on the other hand supplies a constant voltage for a range of loads). Current is switched through the load in one direction to produce a logic state and in the other direction to produce the other logic state. The typical output current is a mere 3.4 mA with a minimum of 2.5 mA, and a maximum of 4.5 mA. The current mode **requires** (as discussed above) that a resistive termination be employed to terminate the signal and to complete the loop as shown in Figure 7. AC or unterminated configurations are not allowed. The 3.4 mA loop current will develop a differential voltage of 340 mV across the 100 $\Omega$  termination resistor which the receiver detects with a 240 mV minimum differential noise margin neglecting resistive line losses (driven signal minus receiver threshold (340 mV – 100 mV = 240 mV). The signal is centered around +1.2V (Driver Offset, V<sub>OS</sub>) with respect to ground as shown in Figure 8. Note that the steady-state voltage (V<sub>SS</sub>) peak-to-peak swing is twice the differential voltage (V<sub>OD</sub>) and is typically 680 mV.

The current mode driver provides substantial benefits over voltage mode drivers, such as an RS-422 driver. Its quiescent current remains relatively flat versus switching frequency. Whereas the RS-422 voltage mode driver increases exponentially in most case between 20 MHz–50 MHz. This is due to the overlap current that flows between the rails of the device when the internal gates switch. Whereas the current mode driver switches a fixed current between its output without any substantial overlap current. This is similar to some ECL and PECL devices, but without the heavy static  $I_{CC}$  requirements of the ECL/PECL designs. LVDS requires > 80% less current than similar PECL devices. AC specifications for the driver are a tenfold improvement over other existing RS-422 drivers.

The fail-safe circuitry guarantees that the outputs are enabled and at a logic "0" (the true output is low and the complement output is high) when the inputs are floating.

The TRI-STATE function allows the driver outputs to be disabled, thus obtaining an even lower power state when the transmission of data is not required.

The footprint of the DS90C031B is the same as the industry standard 26LS31 Quad Differential (RS-422) Driver.

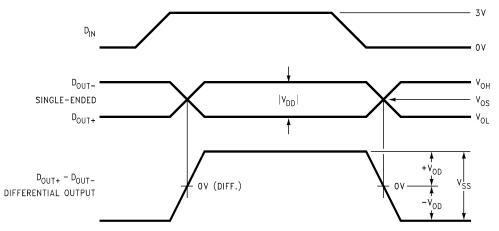
The DS90C031B is electrically similar to the DS90C031, but differs by supporting high impedance LVDS outputs under power-off condition. This allows for multiple or redundant drivers to be used in certain applications. The DS90C031B is offered in a space saving narrow SOIC (150 mil.) package.

For additional LVDS application information, see TI's LVDS Owner's Manual available through TI's website http://www.ti.com/lsds/ti/analog/interface.page.

# DS90C031B

SNLS051B-MARCH 1999-REVISED MARCH 2013

Copyright © 1999–2013, Texas Instruments Incorporated





## **Pin Descriptions**

8

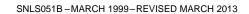
Submit Documentation Feedback

Pin No.	Name	Description
1, 7, 9, 15	D <sub>IN</sub>	Driver input pin, TTL/CMOS compatible
2, 6, 10, 14	D <sub>OUT+</sub>	Non-inverting driver output pin, LVDS levels
3, 5, 11, 13	D <sub>OUT-</sub>	Inverting driver output pin, LVDS levels
4	EN	Active high enable pin, OR-ed with EN*
12	EN*	Active low enable pin, OR-ed with EN
16	V <sub>CC</sub>	Power supply pin, +5V ± 10%
8	GND	Ground pin



www.ti.com

## DS90C031B





2

1.8

1.6

1.4

1.2

1

4.5

16

15.8

15.6

15.4

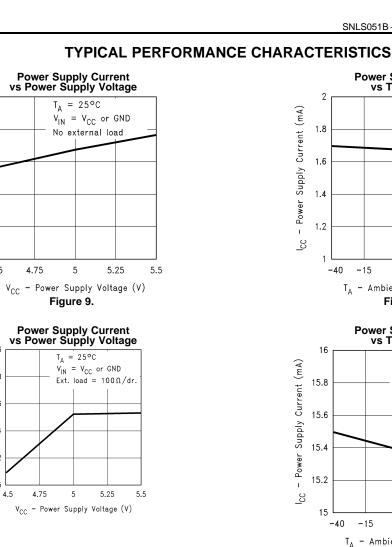
¦ 15.2 \_ප

15

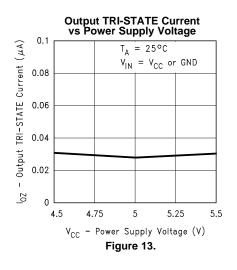
- Power Supply Current (mA)

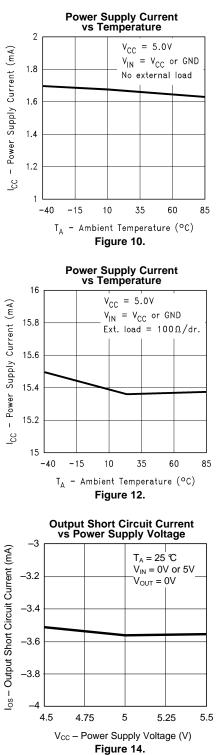
- Power Supply Current (mA)











V<sub>OD</sub> - Differential Output Voltage (mV)

- Output Voltage High (V)

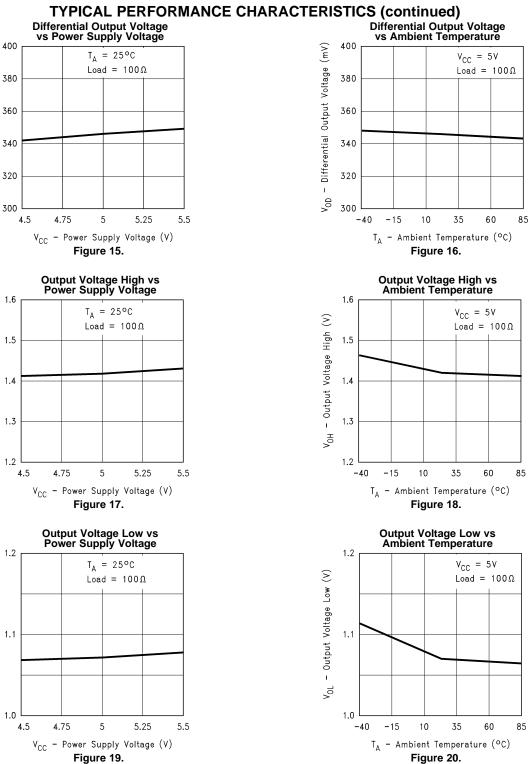
V<sub>OH</sub>

- Output Voltage Low (V)

ر م

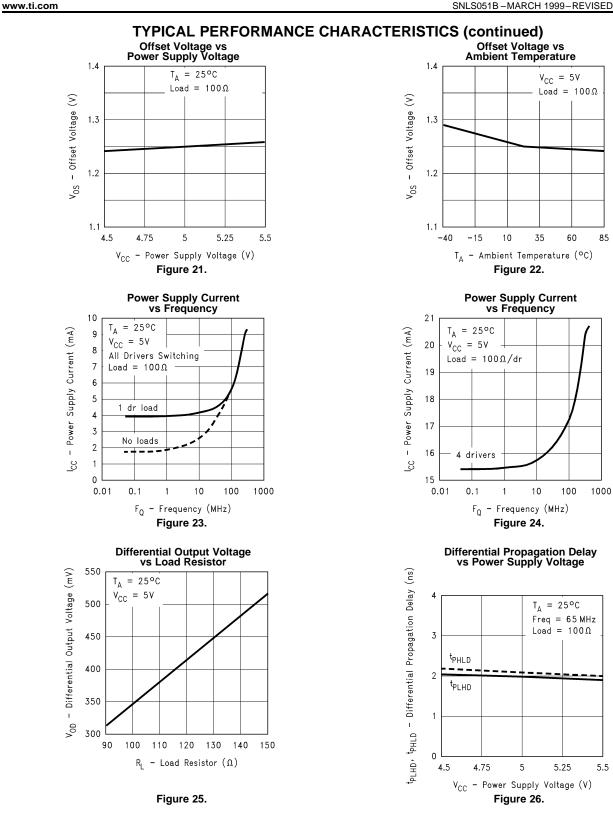


#### SNLS051B-MARCH 1999-REVISED MARCH 2013

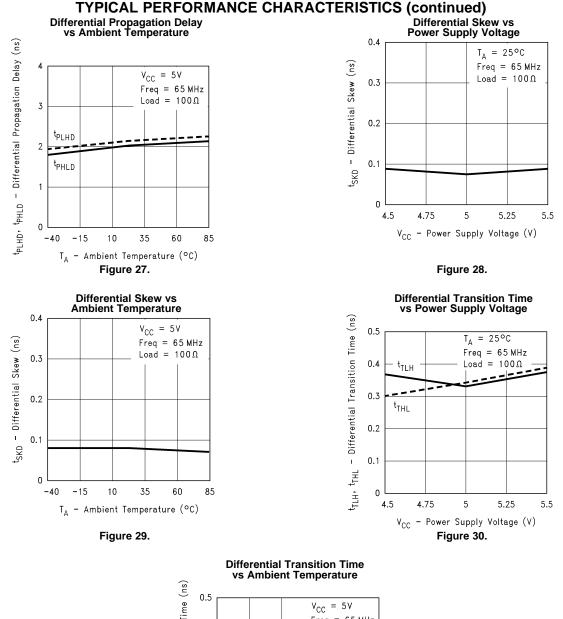


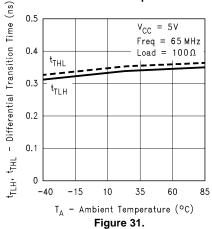


SNLS051B-MARCH 1999-REVISED MARCH 2013



#### SNLS051B-MARCH 1999-REVISED MARCH 2013







SNLS051B-MARCH 1999-REVISED MARCH 2013

## **REVISION HISTORY**

Cł	hanges from Revision A (March 2013) to Revision B	Page
•	Changed layout of National Data Sheet to TI format	12



## **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)		(3)		(4/5)	
DS90C031BTM	ACTIVE	SOIC	D	16	48	TBD	Call TI	Call TI	-40 to 85	DS90C031BTM	Samples
DS90C031BTM/NOPB	ACTIVE	SOIC	D	16	48	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS90C031BTM	Samples
DS90C031BTMX	ACTIVE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	DS90C031BTM	Samples
DS90C031BTMX/NOPB	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS90C031BTM	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(<sup>5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



# PACKAGE OPTION ADDENDUM

23-Sep-2013

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



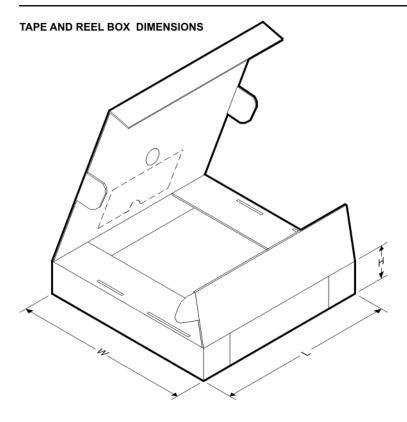
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS90C031BTMX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

# PACKAGE MATERIALS INFORMATION

23-Sep-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS90C031BTMX/NOPB	SOIC	D	16	2500	367.0	367.0	35.0

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconne	ectivity	

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated